

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









TECHNICAL DATA SHEET

6 Lake Street, Lawrence, MA 01841

1-800-446-1158 / (978) 620-2600 / Fax: (978) 689-0803

Website: http://www.microsemi.com

HIGH RELIABILITY SILICON POWER RECTIFIER

Qualified per MIL-PRF-19500/162

- Glass Passivated Die
- Glass to Metal Seal Construction
- VRRM 200 to 1000 Volts

DEVICES					LEVELS
	1N1614	1N4458	1N1614R	1N4458R	JAN
	1N1615	1N4459	1N1615R	1N4459R	JANTX
	1N1616		1N1616R		

ABSOLUTE MAXIMUM RATINGS (T_C = +25°C unless otherwise noted)

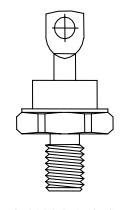
Parameters / Test Conditions				Value	Unit
Peak Repetitive Reverse Voltage 1N1614 1N1614R 1N1615R 1N1615 1N1615R 1N1616 1N1614 1N1615R 1N1615 1N1616R 1N1616R 1N4458R 1N4458R 1N4459R 1N4459R		$ m V_{RWM}$	200 400 600 800 1000	V	
Average Forward Current, $T_C = 150^{\circ}$	I_{F}	15	A		
Peak Surge Forward Current @ $t_p = 8$ $T_C = 150$ °C	I_{FSM}	100	A		
Thermal Resistance, Junction to Case			$R_{\theta JC}$	4.5	°C/W
Operating Case Temperature Range			T _j	-65°C to 175°C	°C
Storage Temperature Range			T _{STG}	-65°C to 175°C	°C

ELECTRICAL CHARACTERISTICS ($T_A = +25^{\circ}C$, unless otherwise noted)

Parameters / Test Conditions			Symbol	Min.	Max.	Unit
Forward Voltage			V_{FM}		1.5	V
$I_{FM} = 15A, T_C = 25^{\circ}C^*$			* FM		1.5	•
Reverse Current						
$V_{RM} = 200, T_C = 25^{\circ}C$	1N1614	1N1614R				
$V_{RM} = 400, T_C = 25^{\circ}C$	1N1615	1N1615R				
$V_{RM} = 600, T_C = 25^{\circ}C$	1N1616	1N1616R	I_{RM}		50	μΑ
$V_{RM} = 800, T_C = 25^{\circ}C$	1N4458	1N4458R				
$V_{RM} = 1000, T_C = 25^{\circ}C$	1N4459	1N4459R				
Reverse Current						
$V_{RM} = 200, T_C = 150^{\circ}C$	1N1614	1N1614R				
$V_{RM} = 400, T_C = 150^{\circ}C$	1N1615	1N1615R				
$V_{RM} = 600, T_C = 150^{\circ}C$	1N1616	1N1616R	I_{RM}		500	μΑ
$V_{RM} = 800, T_C = 150^{\circ}C$	1N4458	1N4458R				
$V_{RM} = 1000, T_C = 150^{\circ}C$	1N4459	1N4459R				

^{*} Pulse test: Pulse width 300 µsec, Duty cycle 2%

Note:



DO-203AA (DO-4)



TECHNICAL DATA SHEET

6 Lake Street, Lawrence, MA 01841 1-800-446-1158 / (978) 620-2600 / Fax: (978) 689-0803 Website: http://www.microsemi.com

HIGH RELIABILITY SILICON POWER RECTIFIER



GRAPHS

FIGURE 1
TYPICAL FORWARD CHARACTERISTICS

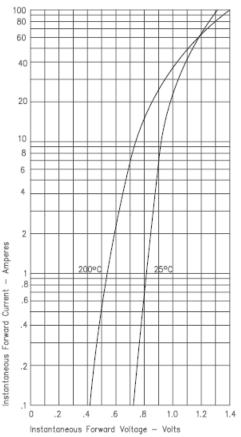


FIGURE 2
TYPICAL REVERSE CHARACTERISTICS

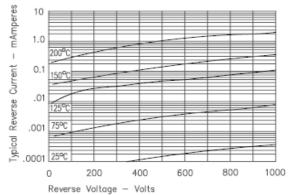


FIGURE 3
FORWARD CURRENT DERATING

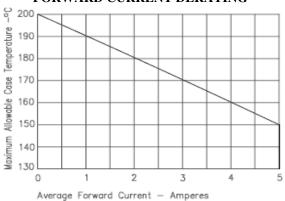
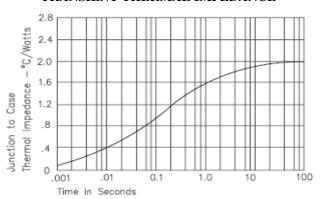


FIGURE 4
TRANSIENT THERMAL IMPEDANCE



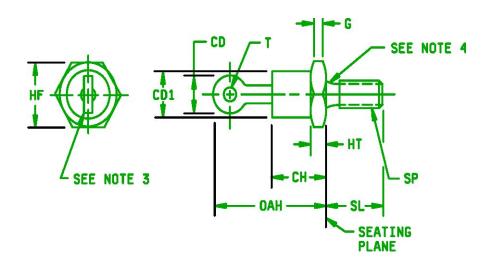


TECHNICAL DATA SHEET

6 Lake Street, Lawrence, MA 01841 1-800-446-1158 / (978) 620-2600 / Fax: (978) 689-0803 Website: http://www.microsemi.com

HIGH RELIABILITY SILICON POWER RECTIFIER

PACKAGE DIMENSIONS



NOTES:

- 1. Dimensions are in inches.
- Millimeter equivalents are given for general information only.
- 3. Angular orientation of this terminal is undefined.
- 4. Diameter of unthreaded portion .189 inch (4.80 mm) maximum; .163 inch (4.14 mm) minimum.
- 5. The A.S.A. thread reference is 10-32UNF2A (unplated).
- 6. The maximum diameter of plated threads shall be basic pitch diameter .169 inch (4.29 mm).
- 7. Unit shall not be damaged by torque of 15 inch-pound applied to 10-32NF2B nut assembled on thread.
- 8. Complete threads shall extend to within 2.5 threads of the seating plane.
- 9. Terminal end shape is unrestricted.
- 10. In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.

Symbol	Inc	hes	Millir	Notes	
	Min	Max	Min	Max	
CD		.250		6.35	9
CD1		.424		10.77	
СН		.405		10.29	
G	.060		1.52		
HF	.424	.437	10.77	11.10	
HT	.075	.175	1.91	4.45	
OAH		.800		20.32	
SP					6,7,8
SL	.422	.453	10.72	11.51	
T	.060		1.52		

Physical dimensions

T4-LDS-0139 Rev. 1 (091749)